

# ST3230C..R SERIES

#### PHASE CONTROL THYRISTORS

#### **Hockey Puk Version**

#### Features

- Double side cooling
- High surge capability
- High mean current
- Fatigue free

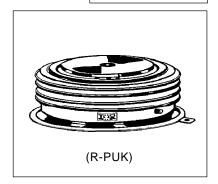
# **Typical Applications**

- DC motor controls
- Controlled DC power supplies
- AC controllers

## Major Ratings and Characteristics

Parameters		ST3230CR	Units	
I <sub>T(AV)</sub>		2785	А	
	@ T <sub>C</sub>	80	°C	
I <sub>T(AV)</sub>		3360	А	
	@ T <sub>hs</sub>	55	°C	
I <sub>T(RMS)</sub>		5970	А	
	@ T <sub>hs</sub>	25	°C	
I <sub>TSM</sub>	@ 50Hz	61200	Α	
	@ 60Hz	64000	А	
I <sup>2</sup> t	@ 50Hz	18730	KA <sup>2</sup> s	
	@ 60Hz	17000	KA <sup>2</sup> s	
V <sub>DRM</sub> /V <sub>RRN</sub>	1	1000 to 1800	V	
t <sub>q</sub>	typical	500	μs	
T <sub>J</sub>	max.	125	°C	

3360A



## **ELECTRICAL SPECIFICATIONS**

# Voltage Ratings

Type number Cod		V <sub>DRM</sub> /V <sub>RRM</sub> , max. repetitive peak and off-state voltage V	V <sub>RSM</sub> , maximum non- repetitive peak voltage V	I <sub>DRM</sub> /I <sub>RRM</sub> max. @ T <sub>C</sub> = 125°C mA
	10	1000	1100	
	12	1200	1300	
ST3230CR	14	1400	1500	250
	16	1600	1700	
	18	1800	1900	

#### On-state Conduction

	Parameter	ST3230CR	Units	Conditions	5	
I <sub>T(AV)</sub>	Max. average on-state current	2785 (1720)	Α			
.(,	@ Case temperature	80	°C	180° conduction, half sine wave		
I <sub>T(AV)</sub>	Max. average on-state current	3360 (1360)	Α	double side (single side [anode side]) cooled		anode side]) cooled
	@ Heatsink temperature	55 (85)	°C			
I <sub>T(RMS)</sub>	Max. RMS on-state current	5970	Α	DC @ 25°C heatsink temperature double side cooled		
I <sub>TSM</sub>	Max. peak, one-cycle	61200		t = 10ms	No voltage	
	non-repetitive surge current	64000	Α	t = 8.3ms	reapplied	
			t = 10ms	50% V <sub>RRM</sub>		
		51300		t = 8.3ms	reapplied	Sinusoidal half wave,
I <sup>2</sup> t	Maximum I2t for fusing	18730		t = 10ms	No voltage	Initial T <sub>C</sub> = 125°C
		17000	KA <sup>2</sup> s	t = 8.3ms	reapplied	
		12000	KA S	t = 10ms	50% V <sub>RRM</sub>	
		10920		t = 8.3ms	reapplied	
V <sub>T(TO)</sub>	Max. value of threshold voltage	0.92	V	$T_J = T_J$ max.		
r <sub>t</sub>	Max. value of on-state slope resistance	0.09	mΩ	$T_J = T_J \text{ max.}$		
V <sub>TM</sub>	Max. on-state voltage	1.3	٧	I <sub>pk</sub> = 2900A, T <sub>C</sub> = 25°C		
I <sub>L</sub> Typical latching current		300	mA	$T_J = 25$ °C, $V_D = 5V$		

# Switching

	Parameter	ST3230CR	Units	Conditions
di/dt	Max. repetitive 50Hz (no repetitive) rate of rise of turned-on current	150 (300)	A/µs	From 67% $V_{DRM}$ to 1000A gate drive 10V, $5\Omega$ , $t_r = 0.5 \mu s$ to 1A, $T_J = T_J$ max.
t <sub>d</sub>	Maximum delay time	4.5		Gate drive 30V, 15 $\Omega$ , V $_{\rm d}$ = 67% V $_{\rm DRM}$ , T $_{\rm J}$ = 25°C Rise time 0.5 $\mu$ s
t <sub>q</sub>	Typical turn-off time	500	μs	$I_T = 1000A, t_p = 1ms, T_J = T_J max, V_{RM} = 50V,$ $dI_{RR}/dt = 2A/\mu s, V_{DR} = 67\% V_{DRM}, dv_{DR}/dt = 8V/\mu s linear$

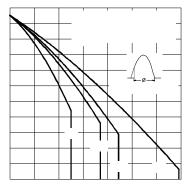


Fig. 1 - Current Ratings Characteristics

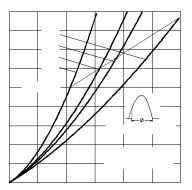


Fig. 2 - Current Ratings Characteristics

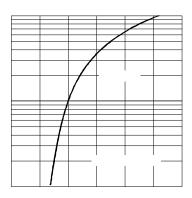


Fig. 3 - On-state Power Loss Characteristics

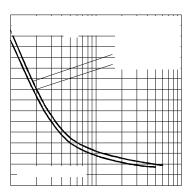


Fig. 4 - On-state Voltage Drop Characteristics

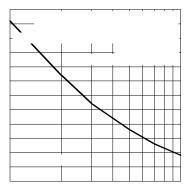


Fig. 5 - Maximum Non-Repetitive Surge Current

Fig. 6 - Maximum Non-Repetitive Surge Current

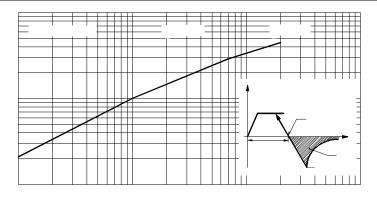


Fig. 7 - Stored Charged

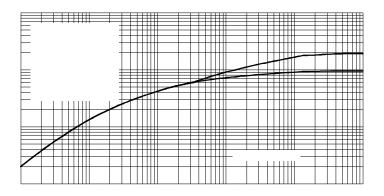


Fig. 8 - Thermal Impedance  $Z_{thJ-C}$  Characteristics

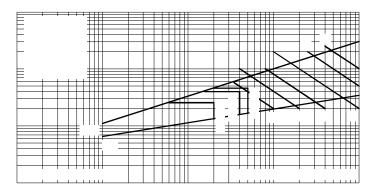


Fig. 9 - Gate Characteristics

## Blocking

Parameter		ST3230CR	Units	Conditions
dv/d	t Maximum linear rate of rise of off-state voltage	500	V/µs	$T_J = T_J$ max. to 67% rated $V_{DRM}$
I <sub>RRM</sub>	Max. peak reverse and off-state leakage current	250	mA	T <sub>J</sub> = 125°C rated V <sub>DRM</sub> /V <sub>RRM</sub> applied

# Triggering

			I		
	Parameter	ST3230CR	Units	Conditions	
$P_GM$	Maximum peak gate power	150	w	t <sub>p</sub> = 100μs	
$P_{G(AV)}$	Maximum average gate power	10	VV		
I <sub>GM</sub>	Max. peak positive gate current	30	Α	Anode positive with respect to cathode	
$V_{GM}$	Max. peak positive gate voltage	30	V	Anode positive with respect to cathode	
-V <sub>GM</sub>	Max. peak negative gate voltage	0.25	V	Anode negative with respect to cathode	
I <sub>GT</sub>	Maximum DC gate current required to trigger	400	mA	T <sub>C</sub> = 25°C, V <sub>DRM</sub> = 5V	
V <sub>GT</sub>	Maximum gate voltage required to trigger	4	V	T <sub>C</sub> = 25°C, V <sub>DRM</sub> = 5V	
V <sub>GD</sub>	DC gate voltage not to trigger	0.25	V	T <sub>C</sub> = 125°C Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated V <sub>DRM</sub> anode-to-cathode applied	

## Thermal and Mechanical Specification

Parameter		ST3230CR	Units	Conditions		
T <sub>J</sub> max. Max. operating temperature		125		On-state (conducting)		
T <sub>stg</sub>	Max. storage temperature range	-55 to 125	°C			
R <sub>thJ-C</sub>	Thermal resistance, junction to case	0.019 0.0095	K/W	DC operation single s		
R <sub>th(C-h)</sub>	Thermal resistance, case to heatsink	0.004 0.002	K/W	Single side cooled Double side cooled	Clamping force 43KN with mounting compound	
F	Mounting force ± 10%	43000 (4400)	N (Kg)			
wt	Approximate weight	1600	g			
Case style		(R-PUK)		See Outline Table		

 $\Delta R_{thJ-C} \ Conduction$  (The following table shows the increment of thermal resistence  $R_{thJ-C}$  when devices operate at different conduction angles than DC)

Conduction angle	Single side	Double side	Units	Conditions
180°	0.0010	0.0010		$T_J = T_J \text{ max.}$
120°	0.0017	0.0017	K/W	
60°	0.0044	0.0044		

#### Ordering Information Table

# **Device Code** 323 0 C 18 R 1 2 3 4 5 6 7 8 Thyristor Essential part number 0 = Converter grade C = Ceramic Puk Voltage code: Code x $100 = V_{RRM}$ (See Voltage Rating Table) R = Puk Case 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads) 1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads) 2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads) 3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads) 8 - Critical dv/dt: None = 500V/µsec (Standard selection) = 1000V/µsec (Special selection)

#### Outline Table

